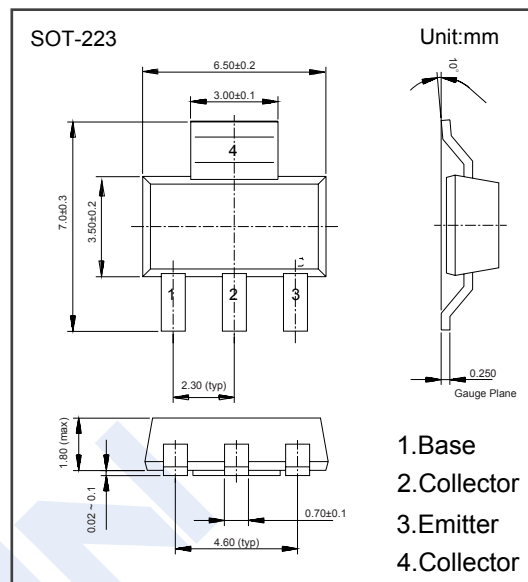
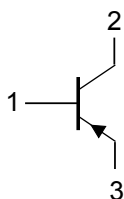


PNP Transistors

BCP69 (KCP69)

■ Features

- High current (max. 1 A)
- Low voltage (max. 20 V)
- Complements to BCP68



■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector - Base Voltage	V_{CB0}	-32	V
Collector - Emitter Voltage	V_{CE0}	-20	
Emitter - Base Voltage	V_{EB0}	-5	
Collector Current - Continuous	I_C	-1	A
Collector Current - Pulse	I_{CP}	-2	
Base Current - Pulse	I_{BP}	-0.2	
Collector Power Dissipation	P_C	1.35	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	91	$^\circ\text{C}/\text{W}$
Thermal Resistance from Junction to Soldering Point	$R_{\theta JS}$	10	
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature range	T_{stg}	-65 to 150	

PNP Transistors

BCP69 (KCP69)

■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector- base breakdown voltage	V_{CB0}	$I_C = -100\ \mu\text{A}$, $I_E = 0$	-32			V
Collector- emitter breakdown voltage	V_{CE0}	$I_C = -1\ \text{mA}$, $I_B = 0$	-20			
Emitter - base breakdown voltage	V_{EB0}	$I_E = -100\ \mu\text{A}$, $I_C = 0$	-5			
Collector-base cut-off current	I_{CB0}	$V_{CB} = -25\ \text{V}$, $I_E = 0$			-100	nA
		$V_{CB} = -25\ \text{V}$, $I_E = 0$, $T_J = 150^\circ\text{C}$			-10	μA
Emitter cut-off current	I_{E0}	$V_{EB} = -5\ \text{V}$, $I_C = 0$			-100	nA
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -1\ \text{A}$, $I_B = -100\ \text{mA}$			-0.5	V
Base - emitter saturation voltage	$V_{BE(sat)}$	$I_C = -1\ \text{A}$, $I_B = -100\ \text{mA}$			-1.2	
Base - emitter voltage	V_{BE}	$V_{CE} = -10\ \text{V}$, $I_C = -5\ \text{mA}$		-0.62		
		$V_{CE} = -1\ \text{V}$, $I_C = -1\ \text{A}$			-1	
DC current gain	h_{FE}	$V_{CE} = -10\ \text{V}$, $I_C = -5\ \text{mA}$	50			
		$V_{CE} = -1\ \text{V}$, $I_C = -500\ \text{mA}$	85		375	
		$V_{CE} = -1\ \text{V}$, $I_C = -1\ \text{A}$	60			
Collector capacitance	C_{ob}	$V_{CB} = -5\ \text{V}$, $I_E = I_C = 0$, $f = 1\ \text{MHz}$		48		pF
Transition frequency	f_T	$V_{CE} = -5\ \text{V}$, $I_C = -10\ \text{mA}$, $f = 100\ \text{MHz}$	40			MHz

■ Classification of $h_{FE}(2)$

Type	BCP69	BCP69-16	BCP69-25
Range	83-375	100-250	160-375
Marking	BCP69	BCP69-16	BCP69-25

■ Typical Characteristics

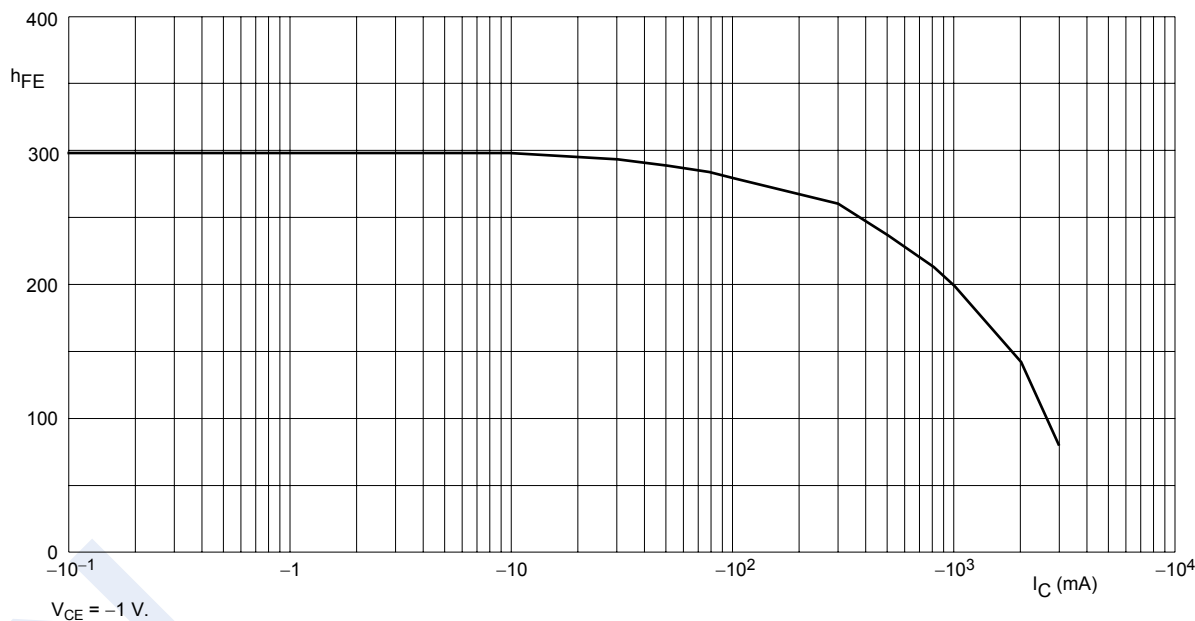


Fig.1 DC current gain; typical values.